

L Number	Hits	Search Text	DB	Time stamp
1	1	5939886.pn.	USPAT; US-PGPUB	2002/09/18 15:04
2	1	5939886.pn.	USPAT; US-PGPUB	2002/09/18 15:04
-	0	("1 and (voltage or volt)").PN.	USPAT; US-PGPUB	2002/09/10 10:12
-	93	156/345.28.ccls.	USPAT; US-PGPUB	2002/09/10 12:09
-	76	156/345.28.ccls. and (voltage or volt)	USPAT; US-PGPUB	2002/09/10 10:38
-	41	(156/345.28.ccls. and (voltage or volt)) and ((substrate or wafer) with voltage)	USPAT; US-PGPUB	2002/09/10 11:12
-	17	((156/345.28.ccls. and (voltage or volt)) and ((substrate or wafer) with voltage)) and impedance	USPAT; US-PGPUB	2002/09/10 11:12
-	28	((156/345.28, 345.24, 345.13, 345.15).ccls. and (substrate or wafer) with voltage) not ((156/345.28).CCLS.)	USPAT; US-PGPUB	2002/09/11 08:58
-	466	h011021/\$.ipc. and ((substrate or wafer) with voltage) and impedance	USPAT; US-PGPUB	2002/09/11 12:14
-	153	c23c016/\$.ipc. and ((substrate or wafer) with voltage) and impedance	USPAT; US-PGPUB	2002/09/10 13:00
-	24	(118/712).ccls. and (substrate or wafer) with voltage	USPAT; US-PGPUB	2002/09/11 11:23
-	5	(118/712).ccls. and ((substrate or wafer) with voltage) and impedance	USPAT; US-PGPUB	2002/09/10 12:58
-	607	(h011021/\$.ipc. and ((substrate or wafer) with voltage) and impedance) or (c23c016/\$.ipc. and ((substrate or wafer) with voltage) and impedance)	USPAT; US-PGPUB	2002/09/10 12:59
-	13	c23c016/\$.ipc. and ((substrate or wafer) with voltage) and impedance	JPO; DERWENT	2002/09/10 13:00
-	102	h011021/\$.ipc. and ((substrate or wafer) with voltage) and impedance	JPO; DERWENT	2002/09/10 13:01
-	105	(c23c016/\$.ipc. and ((substrate or wafer) with voltage) and impedance) or (h011021/\$.ipc. and ((substrate or wafer) with voltage) and impedance)	JPO; DERWENT	2002/09/10 14:19
-	4170	(substrate or wafer or work) and plasma and voltage and current and impedance	USPAT; US-PGPUB	2002/09/10 18:30
-	1674	((substrate or wafer or work) and plasma and voltage and current and impedance) and (vacuum or exhaust) and semiconductor	USPAT; US-PGPUB	2002/09/10 14:27
-	93	(156/345.28).CCLS.	USPAT; US-PGPUB	2002/09/10 19:07
-	237	((substrate or wafer or work) with voltage) and current and impedance and semiconductor and vacuum and probe	USPAT; US-PGPUB	2002/09/10 19:11
-	6	("5198072") or ("5444259") or ("5472561") or ("5576629") or ("5711843") or ("5830310")).PN.	USPAT; US-PGPUB	2002/09/11 08:50
-	69	(156/345.28, 345.24, 345.13, 345.15).ccls. and (substrate or wafer) with voltage	USPAT; US-PGPUB	2002/09/11 10:41
-	31	(substrate or wafer) with (rear or back adj side) with voltage and probe	USPAT; US-PGPUB	2002/09/11 11:22
-	72	(118/712).ccls. and (substrate or wafer) same (Film adj thickness)	USPAT; US-PGPUB	2002/09/11 12:13
-	27912	hitachi.as.	USPAT; US-PGPUB	2002/09/11 12:13
-	427	hitachi.as. and ((substrate or wafer) with voltage) and impedance	USPAT; US-PGPUB	2002/09/11 12:15